## **CNB2003**

## Reflective photosensor

#### ■ Features

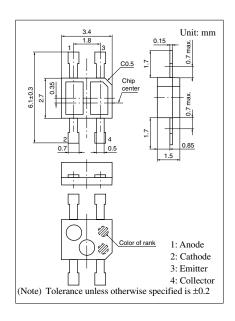
- Reflow-compatible reflective photosensor
- Ultraminiature, thin type: 2.7 mm × 3.4 mm (height: 1.5 mm)

### Applications

• Object sensing, non-contact point SW

## ■ Absolute Maximum Ratings $T_a = 25$ °C

	Symbol	Rating	Unit	
Input (Light	Reverse voltage (DC)	e voltage (DC) $V_R$ 6		V
emitting diode)	Forward current (DC)	$I_F$	50	mA
	Power dissipation *1	$P_{\mathrm{D}}$	75	mW
Output (Photo	Collector current	$I_{C}$	30	mA
transistor)	Collector to emitter voltage	V <sub>CEO</sub>	35	V
	Emitter to collector voltage	V <sub>ECO</sub>	6	V
	Collector power dissipation *2	P <sub>C</sub>	75	mW
Temperature	Operating ambient temperature	T <sub>opr</sub>	-25 to +85	°C
	Storage temperature	T <sub>stg</sub>	-40 to +100	°C

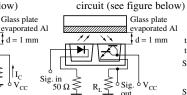


Note) \*1: Input power derating ratio is 1.0 mW/°C at  $T_a \ge 25$ °C.

### ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

	Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Input	Forward voltage (DC)	$V_F$	$I_F = 20 \text{ mA}$		1.2	1.4	V
characteristics	Reverse current (DC)	$I_R$	$V_R = 3 V$			10	μΑ
Output	Collector cutoff current	I <sub>CEO</sub>	$V_{CE} = 10 \text{ V}$			1.0	μΑ
characteristics							
Transfer	Collector current *1	$I_C$	$V_{CC} = 2 \text{ V}, I_F = 4 \text{ mA}, R_L = 100 \Omega, d = 1 \text{ mm}$	0.52		15.0	mA
characteristics	Leakage current	$I_D$	$V_{CC} = 2 \text{ V}, I_F = 4 \text{ mA}, R_L = 100 \Omega$			5.0	μΑ
	Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	$I_F = 4 \text{ mA}, I_C = 0.5 \text{ mA}$			1.2	V
	Response time *2	t <sub>r</sub>	$V_{CC} = 2 \text{ V}, I_{C} = 10 \text{ mA}$		120		μs
		$t_{\rm f}$	$R_L = 100 \Omega$		115		

Note) \*1: Output current (I<sub>C</sub>) measurement method (see figure below) Glass plate



\*2: Response time measurement

Q t<sub>r</sub>: Rise time R t<sub>f</sub>: Fall time Sig. in

Input and output are handled electrically

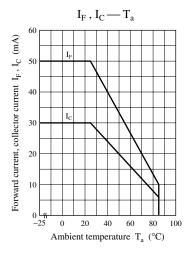
This product is not designed to withstand radiation

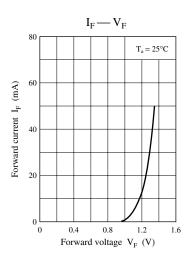
d = 1 mm

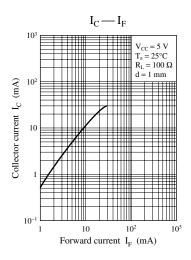
Color indication of classifications

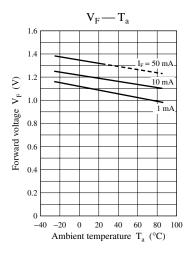
1

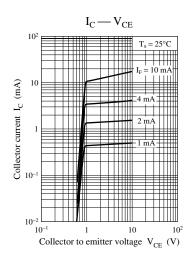
<sup>\*2:</sup> Output power derating ratio is 1.0 mW/°C at  $T_a \ge 25$ °C.

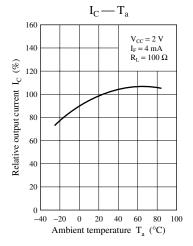


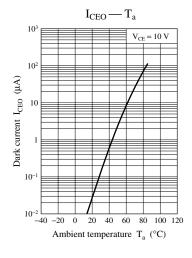


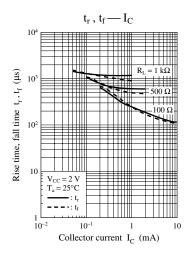


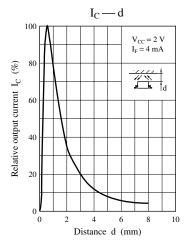












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